

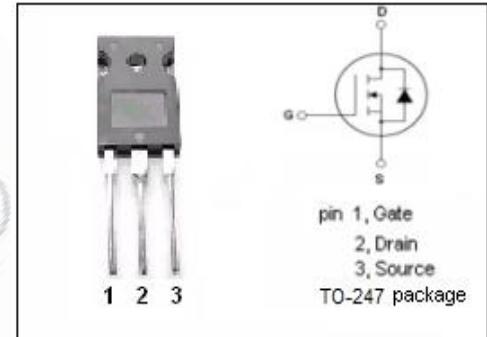
isc N-Channel MOSFET Transistor

IPW65R110CFD

IIPW65R110CFD

• FEATURES

- Static drain-source on-resistance:
 $R_{DS(on)} \leq 110\text{m}\Omega$
- Enhancement mode:
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation



• DESCRIPTION

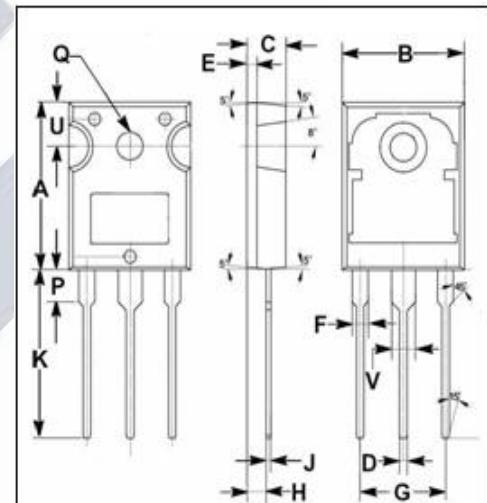
- Suitable for resonant Switching

• ABSOLUTE MAXIMUM RATINGS($T_a=25^\circ\text{C}$)

SYMBOL	PARAMETER	VALUE	UNIT
V_{DSS}	Drain-Source Voltage	650	V
V_{GS}	Gate-Source Voltage	± 20	V
I_D	Drain Current-Continuous	31.2	A
I_{DM}	Drain Current-Single Pulsed	99.6	A
P_D	Total Dissipation @ $T_c=25^\circ\text{C}$	277.8	W
T_j	Max. Operating Junction Temperature	150	$^\circ\text{C}$
T_{stg}	Storage Temperature	-55~150	$^\circ\text{C}$

• THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	MAX	UNIT
$R_{th(j-c)}$	Channel-to-case thermal resistance	0.45	$^\circ\text{C}/\text{W}$
$R_{th(j-a)}$	Channel-to-ambient thermal resistance	62	$^\circ\text{C}/\text{W}$



DIM	mm	
	MIN	MAX
A	19.80	20.20
B	15.40	15.80
C	4.90	5.10
D	0.90	1.10
E	1.40	1.60
F	1.90	2.10
G	10.80	11.00
H	2.40	2.60
J	0.50	0.70
K	19.50	20.50
P	3.90	4.10
Q	3.30	3.50
U	5.20	5.40
V	2.90	3.10

isc N-Channel MOSFET Transistor**IPW65R110CFD****IIPW65R110CFD****ELECTRICAL CHARACTERISTICS** $T_c=25^\circ\text{C}$ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP	MAX	UNIT
BV_{DSS}	Drain-Source Breakdown Voltage	$\text{V}_{\text{GS}}=0\text{V}; \text{I}_D=1\text{mA}$	650			V
$\text{V}_{\text{GS(th)}}$	Gate Threshold Voltage	$\text{V}_{\text{DS}}=\text{V}_{\text{GS}}; \text{I}_D=1.3\text{mA}$	3.5		4.5	V
$\text{R}_{\text{DS(on)}}$	Drain-Source On-Resistance	$\text{V}_{\text{GS}}=10\text{V}; \text{I}_D=12.7\text{ A}$			110	$\text{m}\Omega$
I_{GSS}	Gate-Source Leakage Current	$\text{V}_{\text{GS}}=20\text{V}; \text{V}_{\text{DS}}=0\text{V}$			0.1	mA
I_{DSS}	Drain-Source Leakage Current	$\text{V}_{\text{DS}}=650\text{V}; \text{V}_{\text{GS}}=0\text{V}$			1.5	μA
V_{SD}	Diode forward voltage	$\text{I}_F=19.1\text{A}, \text{V}_{\text{GS}}=0\text{V}$				V